## **SEMICONDUCTOR**

### 25A 10mm LUCAS TYPE PRESS-FIT DIODE

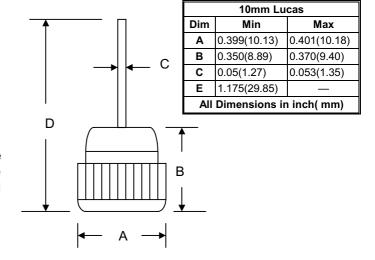
# Data Sheet 2514 Rev.—

#### **Features**

- Diffused Junction
- Low Leakage
- Low Cost
- High Surge Current Capability
- Typical IR less than 20µA

### **Mechanical Data**

- Case: All Copper Case and Components Hermetically Sealed
- Terminals: Contact Areas Readily Solderable
- Polarity: Cathode to Case(Reverse Units Are Available Upon Request and Are Designated By An "R" Suffix, i.e. LD2502R or LD2504R)
- Polarity: Red Color Equals Standard, Black Color Equals Reverse Polarity
- Mounting Position: Any



## Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic		Symbol	LD2500	LD2501	LD2502	LD2503	LD2504	LD2505	LD2506	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		Vrrm Vrwm Vr	50	100	200	300	400	500	600	٧
RMS Reverse Voltage		VR(RMS)	35	70	140	210	280	350	420	V
Average Rectified Output Current @T <sub>A</sub> = 150°C		lo	25							Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)		İFSM	400							Α
Forward Voltage	@I <sub>F</sub> = 50A	VFM	1.05					V		
Peak Reverse Current At Rated DC Blocking Voltage	@T <sub>A</sub> = 25°C @T <sub>A</sub> = 100°C	lгм				20 500				μΑ
Typical Junction Capacitance (Note 1)		Cj	300							pF
Typical Thermal Resistance Junction to Case (Note 2)		$R_{ heta}$ JC	1.0							K/W
Operating and Storage Temperature Range		ТJ, Tsтg	-65 to +175							°C

#### \*Glass passivated forms are available upon request

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

2. Thermal Resistance: Junction to case, single side cooled.